

Supplementary Materials

Self-limited atomic-layer tin-sulfides with high-electron-intensity interface induced ultrathin SEI for fast-charging sodium-ion batteries

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Methods

Computation method of solid surface free energy

Solid surface free energy is an important parameter to evaluate the stability of materials, and several methods are used to calculate it, including dissolving heat method, tension method, splitting force method, theoretical estimation method and contact angle method. Contact angle method is the most commonly used method of estimating solid surface energy at present, possessing the advantages of simple operation and wide application. In the past few decades, many analytical models have been developed to compute surface energy from contact angles such as Fowkes, Owens Wendt Rabel and Kaelbel (OWRK), Van Oss-Chaudhury Good/Lewis acid base theory, Zisman and Neumann. In our work, the OWRK method suitable for universal systems has been adopted. The contact angle of solid materials is measured by sessile drop method.

Wetting phenomena can be illustrated according Young's equation:

$$\gamma_{lv} \cos \theta = \gamma_{sv} - \gamma_{sl}$$

In OWRK method, they separate the interfacial tension of liquid and surface energy of solid with two molecules, including dispersive interactions (γ_{lv}^D and γ_{sv}^D) and polar interactions (γ_{lv}^P and γ_{sv}^P). The combining rule provided by OWRK model is indicated below.

$$\gamma_{sl} = \gamma_{sv} + \gamma_{lv} - 2(\sqrt{\gamma_{sv}^D \gamma_{lv}^D} + \sqrt{\gamma_{sv}^P \gamma_{lv}^P})$$

We can get:

$$\gamma_{lv}(1 + \cos \theta) = 2(\sqrt{\gamma_{sv}^D \gamma_{lv}^D} + \sqrt{\gamma_{sv}^P \gamma_{lv}^P})$$

In this equation, γ_{sv}^D and γ_{sv}^P are unknown. Firstly, at least two liquids with known dispersive and polar parts of surface tensions are needed. Then, contact angles of two liquids on the solid surface are tested. The value of γ_{sv}^D and γ_{sv}^P can be calculated.

$$\gamma_{sv} = \gamma_{sv}^D + \gamma_{sv}^P$$

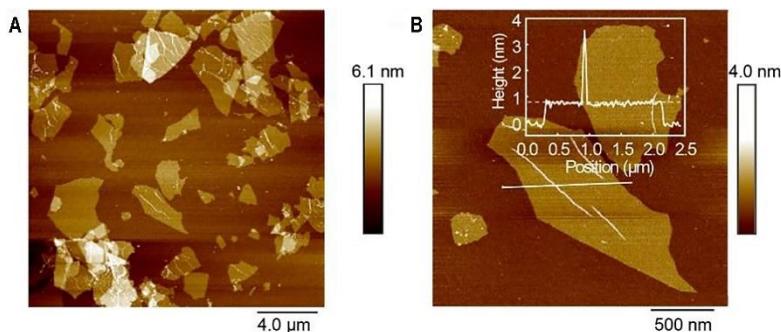
So, the solid surface free energy (γ_{sv}) can be determined.

More detailed information of computation method of solid surface free energy is referred to literature.

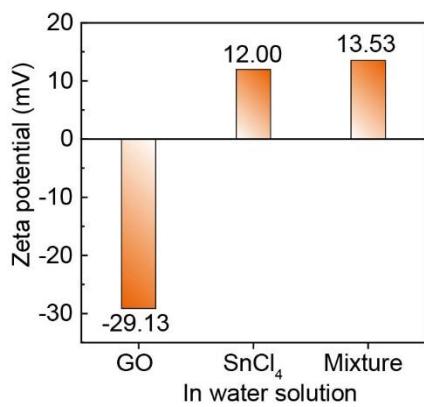
DFT computation Methods

All spin-polarized DFT calculations were performed under the general gradient approximation using the Perdew–Burke–Ernzerhof functionals as implemented in the

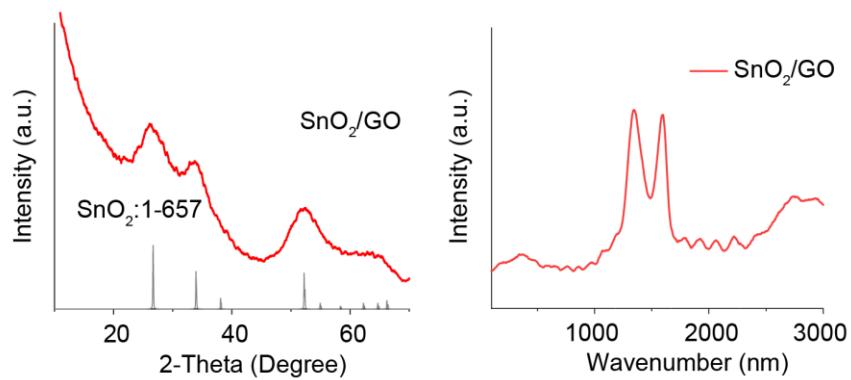
Vienna ab initio simulation package (VASP).^[2, 3] The core-electrons were treated with the projector augmented wave method. The kinetic cutoff for plane-waves was set as 500 eV. For bulk calculations, a $2 \times 2 \times 3$ supercell was used. DFT-D2 correction was added to describe the van der Waals interactions. The reciprocal space was sampled on a Monkhorst-Pack $10 \times 10 \times 10$ meshes. The electron self-consistent calculations were converged to 10^{-4} eV. For structural relaxation, both the ion positions and the lattice parameters were allowed to change until the Hellman–Feynman forces on each ion went below 10^{-2} eV \AA^{-1} . For the surface calculations, a slab model was built constituting three SnS_2 layers with a 2×2 periodic surface unit and the single graphene layer with a 3×3 supercell. To avoid self-interaction of the slab, a vacuum of 15 \AA was used. The reciprocal space was sampled on a Monkhorst-Pack $7 \times 7 \times 1$ meshes. The structural relaxation was performed in the same way as the bulk calculation, except the in-plane lattice parameters which were fixed at a serial of values around the bulk value of SnS_2 and the lowest-lying one in energy was selected. The diffusion barriers of Na^+ ions were calculated using the climb-image nudged elastic band theory. The initial band was constructed by linear interpolation of seven images. For the convergence of the elastic band, a force convergence of 10^{-2} eV \AA^{-1} was used.



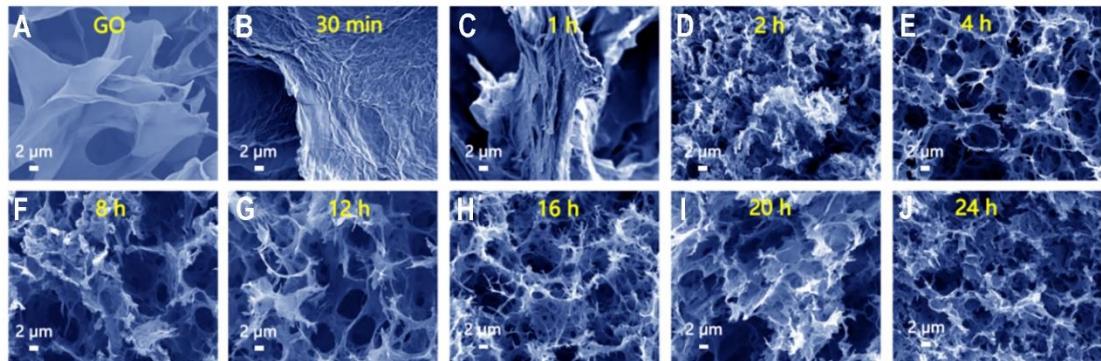
Supplementary Figure 1. Structural characterization of GO. (A) AFM image and (B) height profiles (inset image) of obtained GO raw materials¹. The white lines represent the existence of folds due to GO sheets are hard to completely spread on the substrate.



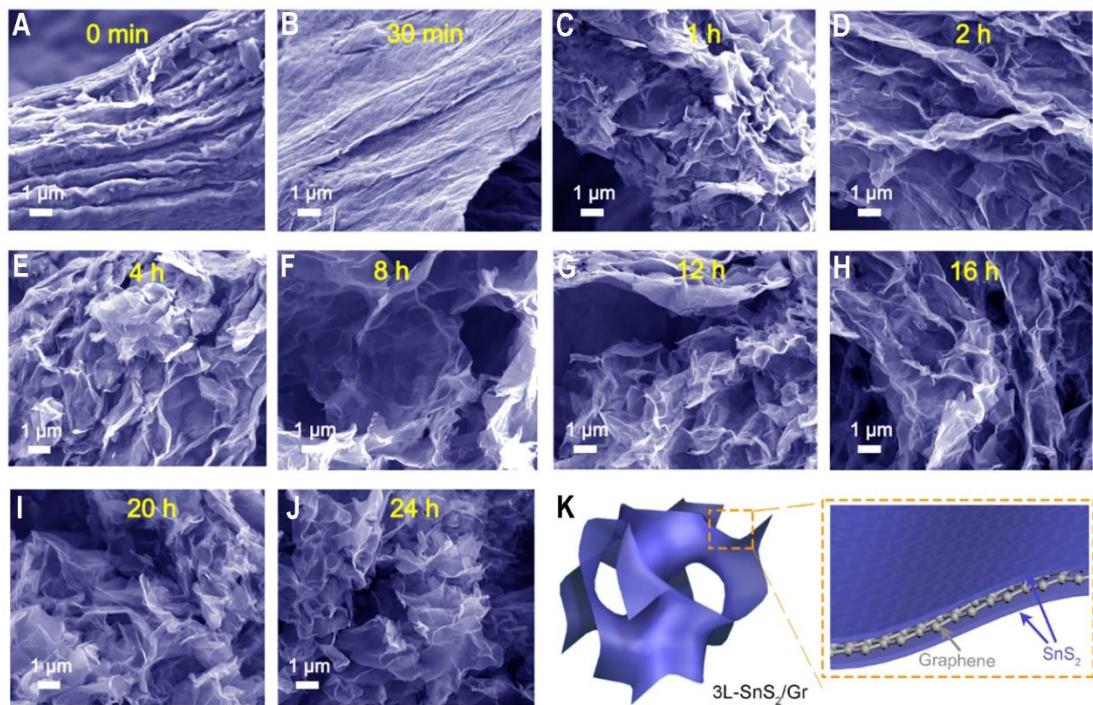
Supplementary Figure 2. Zeta potential of GO, SnCl_4 and their mixture in water.



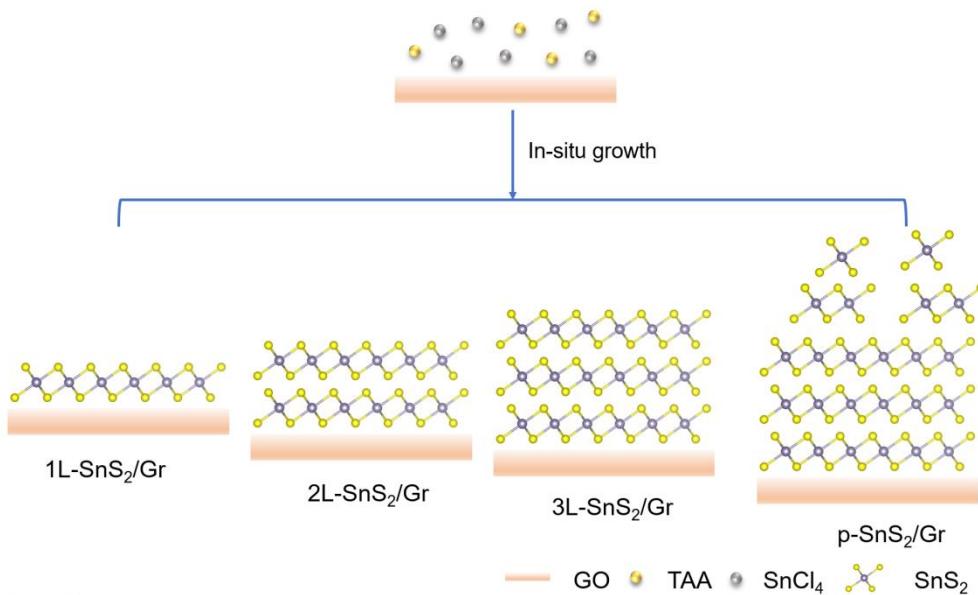
Supplementary Figure 3. XRD and Raman spectra of SnO_2/GO .



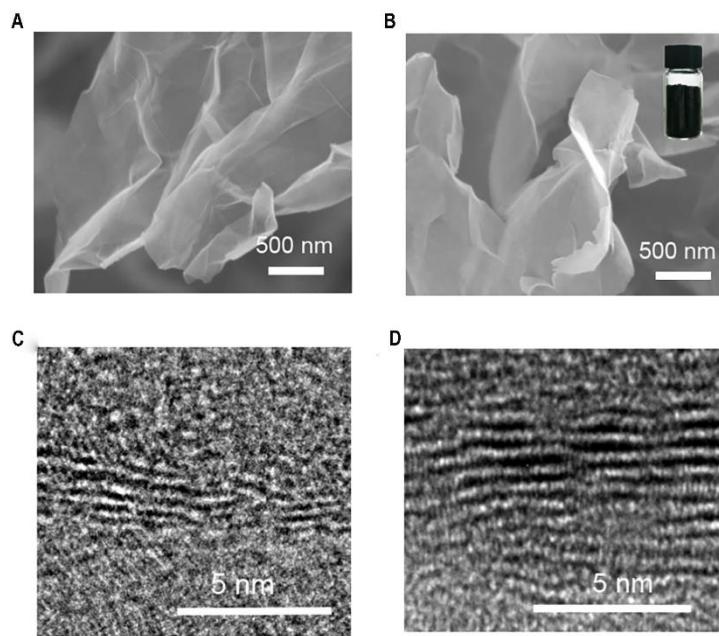
Supplementary Figure 4. (A-J) SEM images of GO at 0 min, 30 min, 1 h, 2 h, 4 h, 8 h, 12 h, 16 h, 20 h, 24 h.



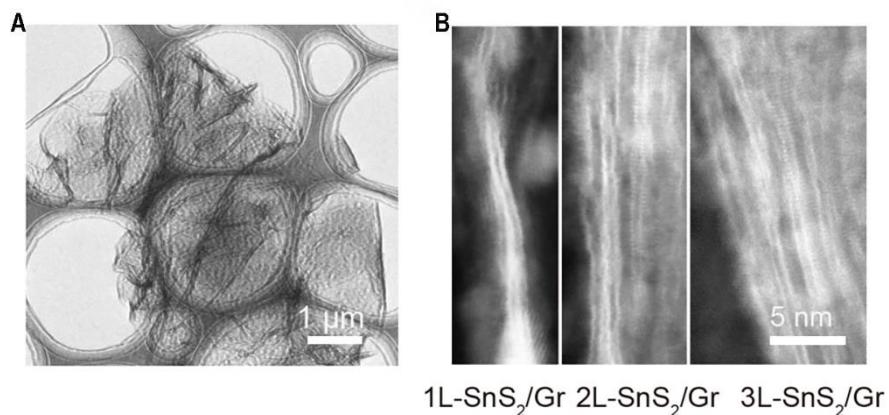
Supplementary Figure 5. (A-J) SEM images of 3L-SnS₂/Gr at 0 min, 30 min, 1 h, 2 h, 4 h, 8 h, 12 h, 16 h, 20 h, 24 h; (K) schematic illustration of 3L-SnS₂/Gr.



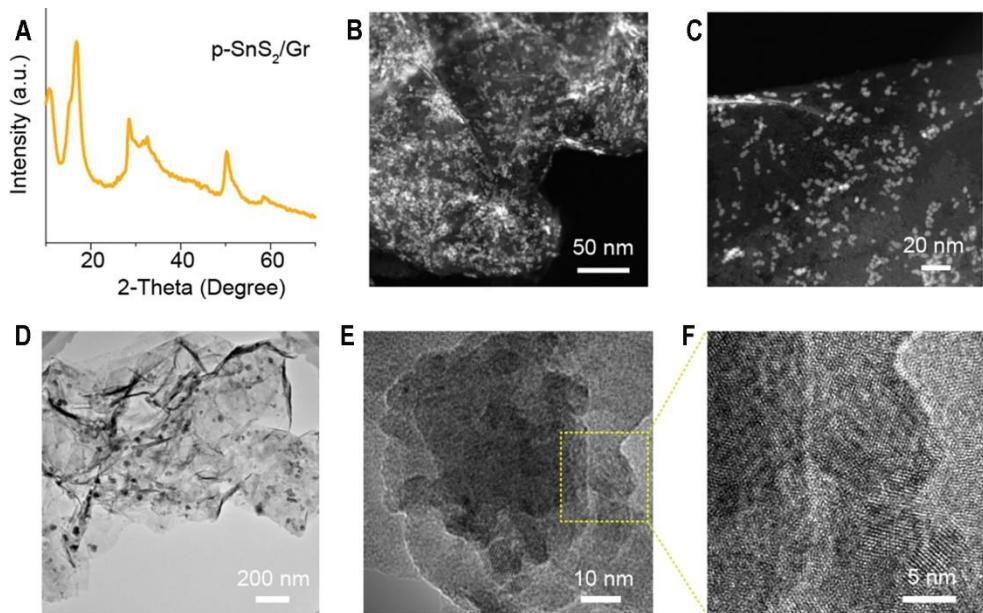
Supplementary Figure 6. Synthetic process of 1L-SnS₂/Gr, 2L-SnS₂/Gr, 3L-SnS₂/Gr and p-SnS₂/Gr.



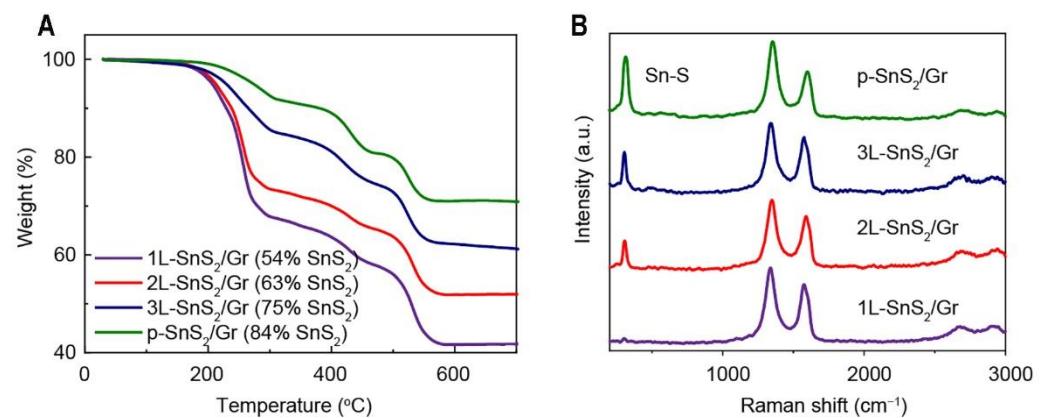
Supplementary Figure 7. (A and B) SEM images of 2L-SnS₂/Gr and 3L-SnS₂/Gr, inset of b the photograph of 3L-SnS₂/Gr; (C and D) TEM images of 2L-SnS₂/Gr and 3L-SnS₂/Gr.



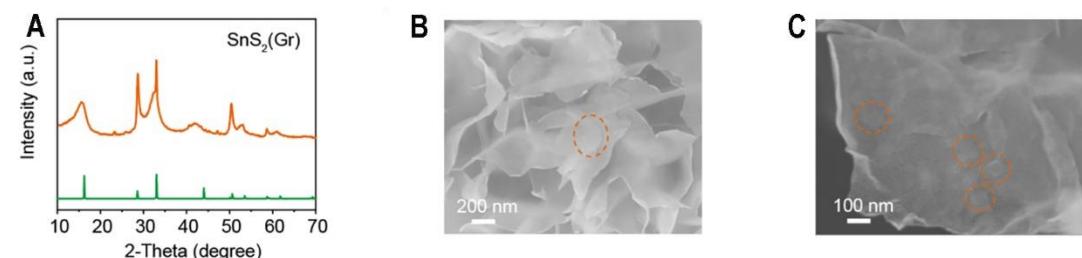
Supplementary Figure 8. (A) TEM image of 1L-SnS₂/Gr; (B) HAADF-STEM images of 1L-SnS₂/Gr, 2L-SnS₂/Gr and 3L-SnS₂/Gr.



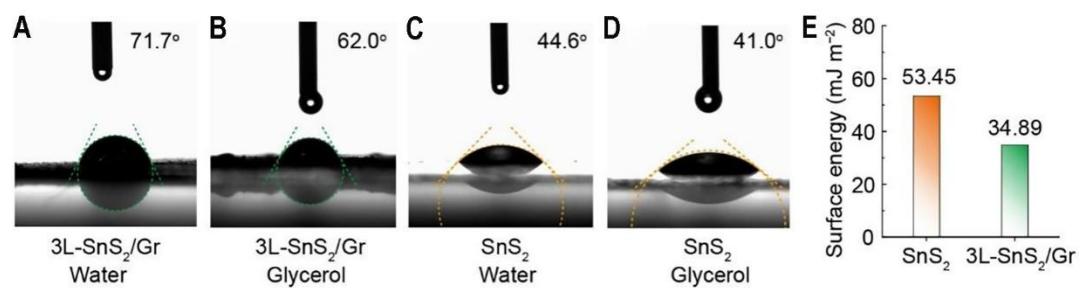
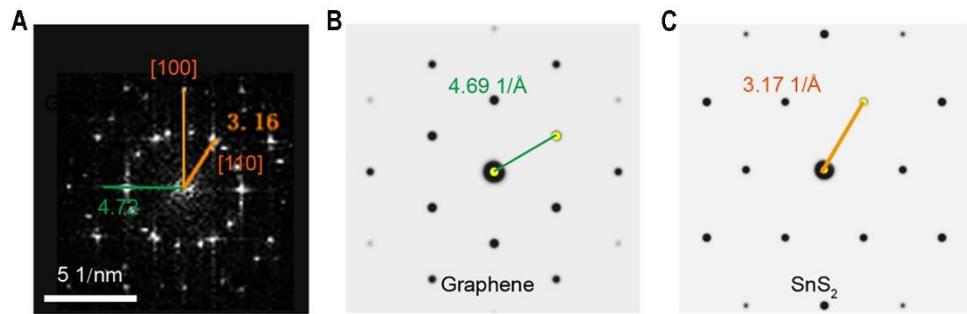
Supplementary Figure 9. Structural characterization of p-SnS₂/Gr. (A) XRD pattern; (B and C) HAADF-STEM images; (D) TEM image; (E and F) HRTEM images.

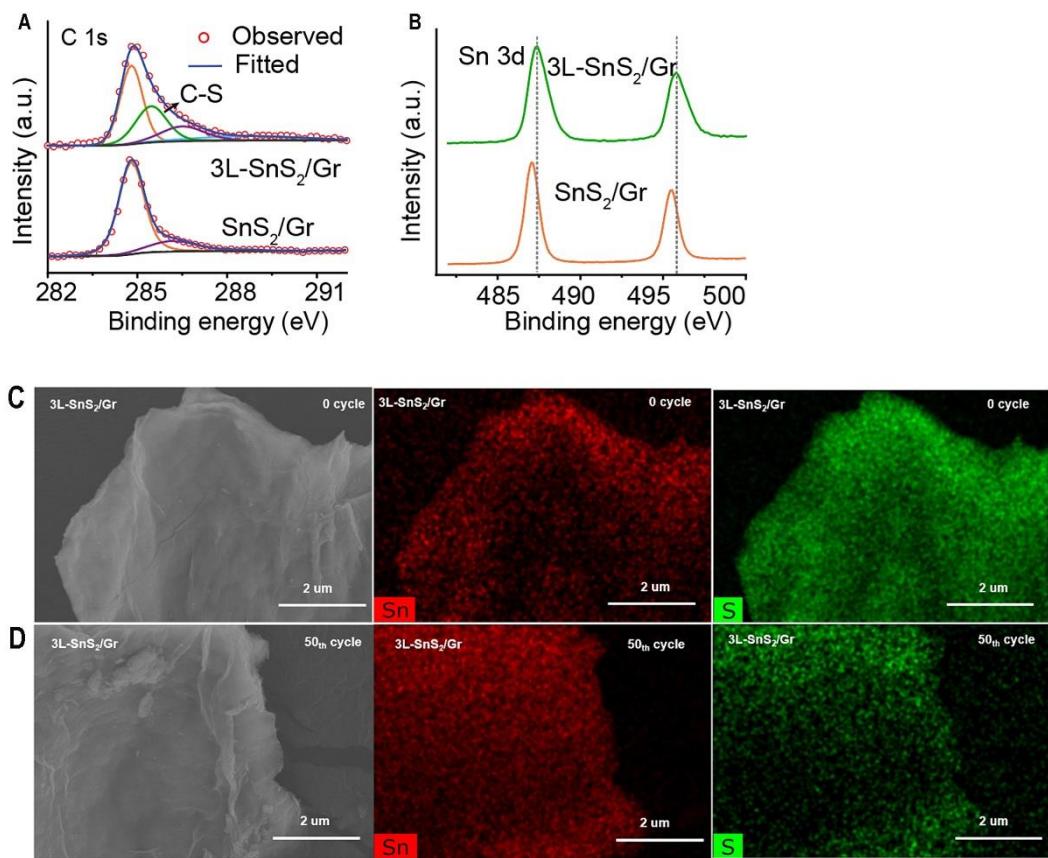


Supplementary Figure 10. (A) TGA curves and (B) Raman spectra of 1L-SnS₂/Gr, 2L-SnS₂/Gr, 3L-SnS₂/Gr and p-SnS₂/Gr.

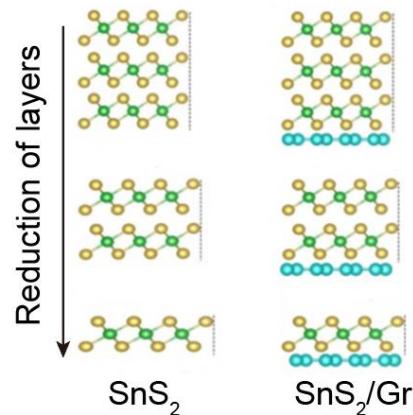


Supplementary Figure 11. (A) XRD of SnS₂(Gr); (B and C) SEM images of SnS₂(Gr).

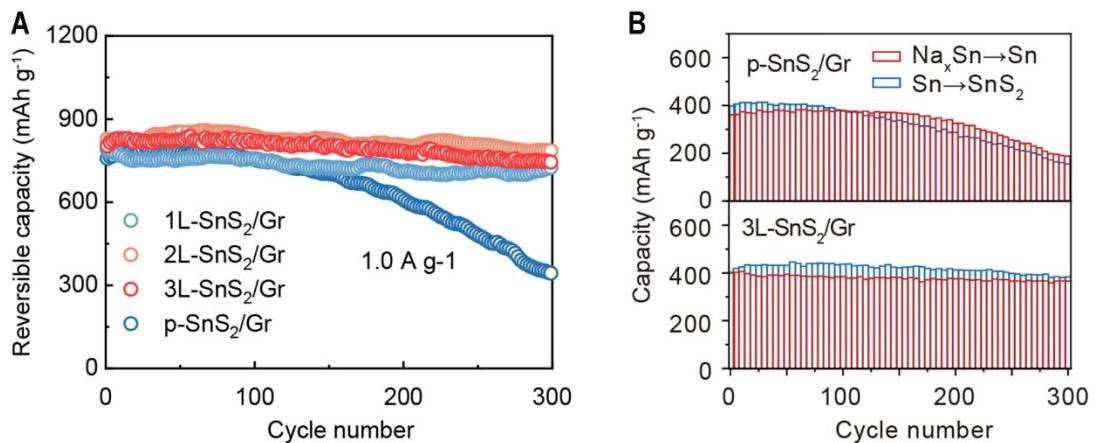




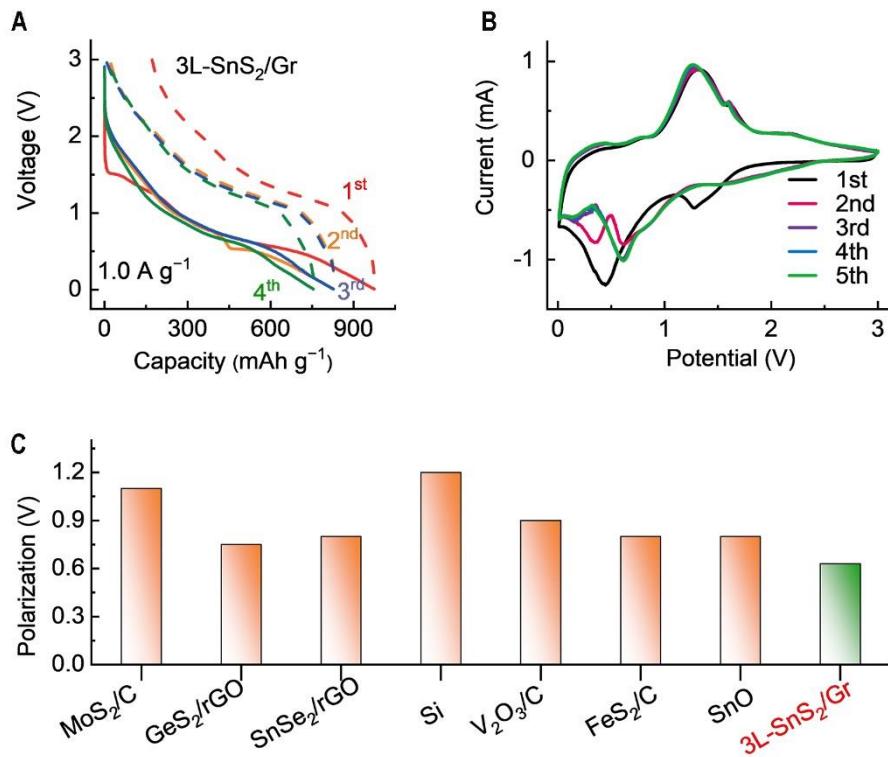
Supplementary Figure 14. (A and B) High resolution C 1s and Sn 3d spectra of 3L-SnS₂/Gr and SnS₂/Gr; (C and D) The SEM and EDS images of 3L-SnS₂/Gr at 0 cycle and 50 cycle comparison.



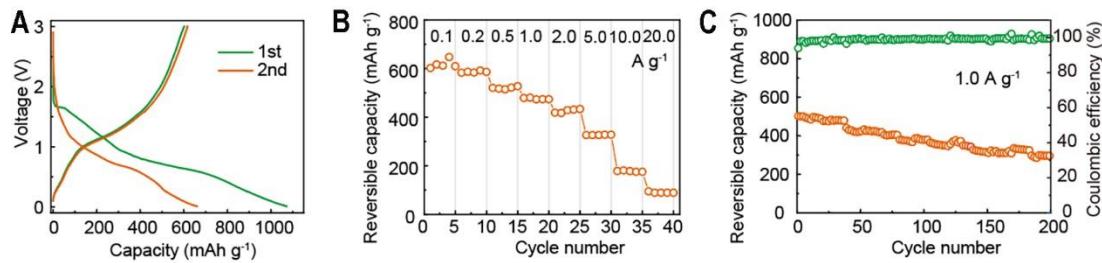
Supplementary Figure 15. (A) Schematic illustration of SnS₂ and SnS₂/Gr with reduction of layers.



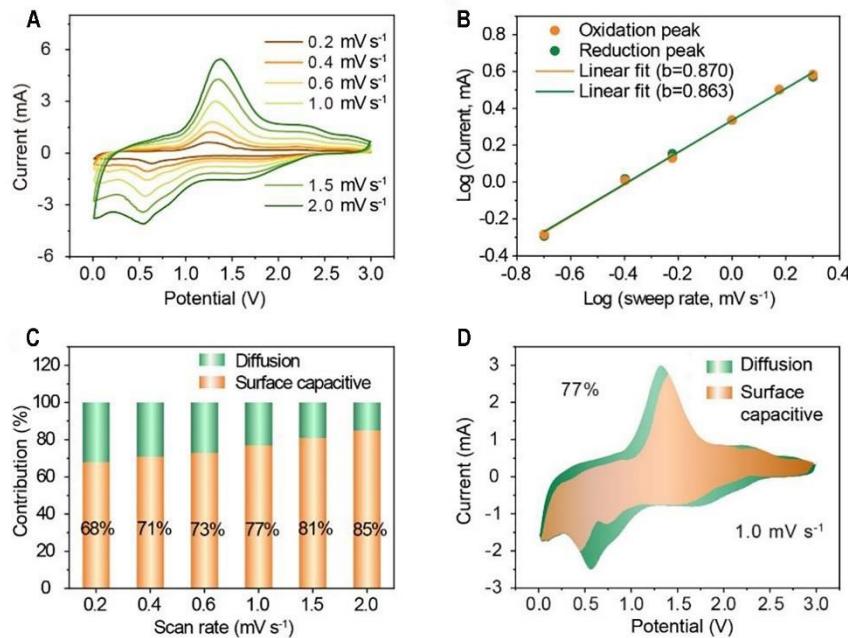
Supplementary Figure 16. (A) Cycling stability of 1L-SnS₂/Gr, 2L-SnS₂/Gr and 3L-SnS₂/Gr; (B) Capacity analysis of conversion and alloy reaction for 3L-SnS₂/Gr and p-SnS₂/Gr.



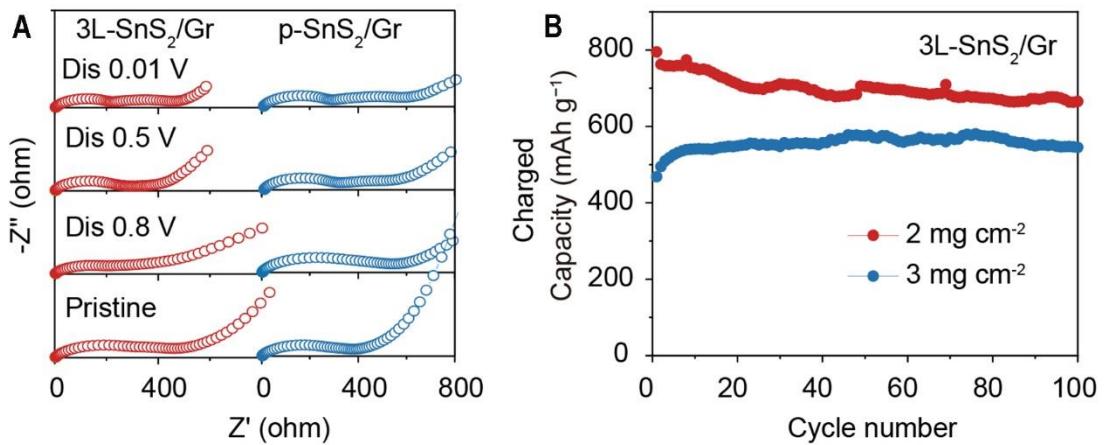
Supplementary Figure 17. Discharge/charge curve and midpoint voltage difference. (A) discharge/charge curve of 3L-SnS₂/Gr at 1.0 A g⁻¹; (B) CV of 3L-SnS₂/Gr at 1-5 cycles; (C) Potential voltage difference of various anode material^{2, 3, 4, 5, 6, 7, 8} in SIBs.



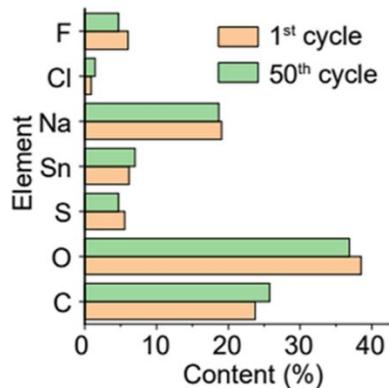
Supplementary Figure 18. (A) Charge/discharge curves; (B) rate performance; (C) cycling stability of SnS₂/Gr.



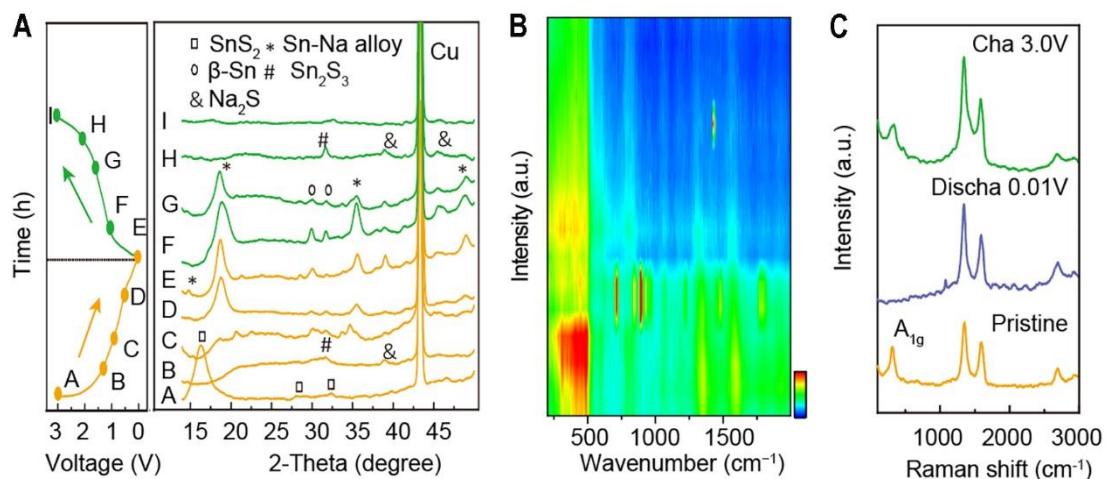
Supplementary Figure 19. Electrochemical reaction kinetics analysis of as-obtained 3L-SnS₂/Gr electrode. (A) CV curves of 3L-SnS₂/Gr at various scan rates for 0.2–2.0 mV s⁻¹; (B) Determination of the b-value using the relationship between anodic/cathodic peak current and scan rate; (C) surface capacitive contribution in 3L-SnS₂/Gr at various scan rates; (D) Separation of the capacitive and diffusion currents in 3L-SnS₂/Gr at a scan rate of 1.0 mV s⁻¹, respectively.



Supplementary Figure 20. (A) EIS spectra for 3L-SnS₂/Gr and p-SnS₂/Gr at pristine state, discharging to 0.8 V, 0.5 V, and 0.01 V; (B) Cycling stability of 3L-SnS₂/Gr at different loading content.



Supplementary Figure 21. The elements content comparation of SEI on the 3L-SnS₂/Gr after 1 cycle and 50 cycles.



Supplementary Figure 22. (A) *Ex-situ* XRD patterns collected at various voltage; (B) *In-situ* Raman spectra during discharging process; (C) *Ex-situ* Raman spectrum of 3L-SnS₂/Gr.

the electrode before cycling, after first discharge to 0.01 V and after first charge to 3.0 V.

Supplementary Table 1. Comparison of electrochemical performance of different anode materials in sodium-ion batteries

Materials	Reversible capacity (mAh g ⁻¹) at low current densities	High rate capacity (mAh g ⁻¹)	Reversible capacity after long cycle (mAh g ⁻¹)	Decay per cycle
3L-SnS ₂ /Gr	953 (0.1 A g ⁻¹)	686 (5 A g ⁻¹) 569 (10 A g ⁻¹) 264 (30 A g ⁻¹)	549 (10 A g ⁻¹ , 600 cycles)	0.005%
SnS ₂ @CNT ⁹	523 (0.1 A g ⁻¹)	441 (5 A g ⁻¹)	525 (0.2 A g ⁻¹ , 100 cycles)	0.25%
CoSe-rGO ¹⁰	491 (0.1 A g ⁻¹)	267 (20 A g ⁻¹)	401 (1 A g ⁻¹ , 100 cycles)	0.118%
GeS ₂ /rGO ¹¹	783 mAh g ⁻¹ (0.1 A g ⁻¹)	616 (5 A g ⁻¹)	720 (0.1 A g ⁻¹ , 100 cycles)	0.106%
MoS ₂ -rGO/HCS ³	646 (0.1 A g ⁻¹)	364 (5 A g ⁻¹)	443 (1.0 A g ⁻¹ , 500 cycles)	0.015%
VS ₄ ¹²	580 (0.1 A g ⁻¹)	173 (10 A g ⁻¹)	402 (0.5 A g ⁻¹ , 300 cycles)	0.007%
Fe ₃ N@C ¹³	356 (0.1 A g ⁻¹)	248 (2.0 A g ⁻¹)	280 (0.4 A g ⁻¹ , 300 cycles)	0.04%
SnS@C nanotubes ¹⁴	450 (0.1 A g ⁻¹)	290 (5 A g ⁻¹)	469 (0.2 A g ⁻¹ , 100 cycles)	0.09%

			cycles)		
SnS ₂ /GCA ¹⁵	630 (0.2 A g ⁻¹)	301 (10 A g ⁻¹)	260 (3 A g ⁻¹ , 1000 cycles)	0.03%	
FeS@Fe ₃ C@ Graphitic ¹⁶	750 (0.1 A g ⁻¹)	292 (5 A g ⁻¹)	575.7 (0.1 A g ⁻¹ , 200 cycles)	0.28%	
Sb ₂ S ₅ -GF ⁷	843 (0.1 A g ⁻¹)	525 (10.0 A g ⁻¹)	748 (0.2 A g ⁻¹ , 300 cycles)	0.028%	
SnSe NS ¹⁷	400 (0.1 A g ⁻¹)	106 (20.0 A g ⁻¹)	183 (2 A g ⁻¹ , 100 cycles)	0.37%	
CoS _x ¹⁸	800 (0.1 A g ⁻¹)	479 (2.0 A g ⁻¹)	572 (0.5 A g ⁻¹ , 100 cycles)	0.17%	
FeS ₂ @C ⁶	560 (0.1 A g ⁻¹)	403 (5 A g ⁻¹)	330 (2 A g ⁻¹ , 800 cycles)	0.0425%	

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